8-Stage Shift/Store Register with Three-State Outputs

The MC14094B combines an 8-stage shift register with a data latch for each stage and a 3-state output from each latch.

Data is shifted on the positive clock transition and is shifted from the seventh stage to two serial outputs. The Q_S output data is for use in high-speed cascaded systems. The Q_S output data is shifted on the following negative clock transition for use in low-speed cascaded systems.

Data from each stage of the shift register is latched on the negative transition of the strobe input. Data propagates through the latch while strobe is high.

Outputs of the eight data latches are controlled by 3-state buffers which are placed in the high-impedance state by a logic Low on Output Enable.

Features

- 3-State Outputs
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- Input Diode Protection
- Data Latch
- Dual Outputs for Data Out on Both Positive and Negative Clock Transitions
- Useful for Serial-to-Parallel Data Conversion
- Pin-for-Pin Compatible with CD4094B
- These are Pb-Free Devices*

MAXIMUM RATINGS (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{in} , V _{out}	Input or Output Voltage Range (DC or Transient)	-0.5 to V _{DD} + 0.5	V
I _{in} , I _{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
P _D	Power Dissipation, per Package (Note 1)	500	mW
T _A	Ambient Temperature Range	-55 to +125	°C
T _{stg}	T _{stg} Storage Temperature Range –65		°C
TL	Lead Temperature (8–Second Soldering)	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



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MARKING DIAGRAMS



PDIP-16 P SUFFIX CASE 648 16<u>ኩሉ ሉሉ ሉሉ ሉ</u> MC14094BCP o AWLYYWWG 1 ሥራ ሁሉ ሁሉ ሁሉ ሁሉ



SOIC-16 D SUFFIX CASE 751B





TSSOP-16 DT SUFFIX CASE 948F





SOEIAJ-16 F SUFFIX CASE 966



A = Assembly Location

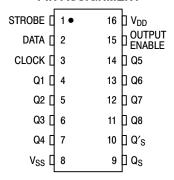
WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G or ■ = Pb-Free Indicator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PIN ASSIGNMENT



TRUTH TABLE

	Output		Parallel Outputs S		Parallel Outputs		Outputs
Clock	Enable	Strobe	Data	Q1	Q _N	Q _S *	Q′s
	0	Х	Х	Z	Z	Q7	No Chg.
~	0	Х	Х	Z	Z	No Chg.	Q7
	1	0	Х	No Chg.	No Chg.	Q7	No Chg.
	1	1	0	0	Q _N -1	Q7	No Chg.
	1	1	1	1	Q _N -1	Q7	No Chg.
~	1	1	1	No Chg.	No Chg.	No Chg.	Q7

Z = High Impedance X = Don't Care

ORDERING INFORMATION

Device	Package	Shipping [†]
MC14094BCPG	PDIP-16 (Pb-Free)	500 Units / Rail
MC14094BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14094BDR2G	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel
MC14094BDTR2G	TSSOP-16*	2500 Units / Tape & Reel
MC14094BFG	SOEIAJ-16 (Pb-Free)	50 Units / Rail
MC14094BFELG	SOEIAJ-16 (Pb-Free)	2000 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *This package is inherently Pb-Free.

^{*} At the positive clock edge, information in the 7th shift register stage is transferred to Q8 and Q_S.

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

			V_{DD}	- 5	5°C		25°C		125	5°C	
Characteristic		Symbol	Vdc	Min	Max	Min	Typ ⁽²⁾	Max	Min	Max	Unit
Output Voltage "0 V _{in} = V _{DD} or 0	" Level	V _{OL}	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
$V_{in} = 0 \text{ or } V_{DD}$ "1	" Level	V _{OH}	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	Vdc
Input Voltage "0 $(V_O = 4.5 \text{ or } 0.5 \text{ Vdc})$ $(V_O = 9.0 \text{ or } 1.0 \text{ Vdc})$ $(V_O = 13.5 \text{ or } 1.5 \text{ Vdc})$	" Level	V _{IL}	5.0 10 15	- - -	1.5 3.0 4.0	- - -	2.25 4.50 6.75	1.5 3.0 4.0	- - -	1.5 3.0 4.0	Vdc
"1 $(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$	" Level	V _{IH}	5.0 10 15	3.5 7.0 11	- - -	3.5 7.0 11	2.75 5.50 8.25	- - -	3.5 7.0 11	- - -	Vdc
Output Drive Current $ (V_{OH} = 2.5 \text{ Vdc}) $ $ (V_{OH} = 4.6 \text{ Vdc}) $ $ (V_{OH} = 9.5 \text{ Vdc}) $ $ (V_{OH} = 13.5 \text{ Vdc}) $	Source	Іон	5.0 5.0 10 15	- 3.0 - 0.64 - 1.6 - 4.2	- - -	- 2.4 - 0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8	- - -	- 1.7 - 0.36 - 0.9 - 2.4	- - -	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	I _{OL}	5.0 10 15	0.64 1.6 4.2	- - -	0.51 1.3 3.4	0.88 2.25 8.8	- - -	0.36 0.9 2.4	- - -	mAdc
Input Current		I _{in}	15	-	± 0.1	-	±0.00001	± 0.1	-	± 1.0	μAdc
Input Capacitance (V _{in} = 0)		C _{in}	-	-	-	-	5.0	7.5	-	-	pF
Quiescent Current (Per Package)		I _{DD}	5.0 10 15	- - -	5.0 10 20	- - -	0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μAdc
Total Supply Current ⁽³⁾ ⁽⁴⁾ (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs buffers switching)		lτ	5.0 10 15			$I_T = ($	1.1 μΑ/kHz) f 14 μΑ/kHz) f 40 μΑ/kHz) f	+ I _{DD}			μAdc
3-State Output Leakage Cur	rent	I_{TL}	15	_	± 0.1	_	± 0.0001	± 0.1	-	± 3.0	μΑ

^{2.} Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in μA (per package), C_L in pF, $V = (V_{DD} - V_{SS})$ in volts, f in kHz is input frequency, and k = 0.001.

^{3.} The formulas given are for the typical characteristics only at 25°C.
4. To calculate total supply current at loads other than 50 pF:

Characteristic	Symbol	V _{DD} Vdc	Min	Typ ⁽⁶⁾	Max	Unit
Output Rise and Fall Time t _{TLH} , t _{THL} = (1.35 ns/pF) C _L + 33 ns	t _{TLH} , t _{THL}	5.0	_	100	200	ns
t _{TLH} , t _{THL} = (1.65 hs/pF) C _L + 20 hs	IHL	10		50	100	
t_{TLH} , $t_{THL} = (0.4 \text{ ns/pF}) C_L + 20 \text{ ns}$		15	_	40	80	
Propagation Delay Time (Figure 1)	t _{PLH} ,					ns
Clock to Serial out QS	t _{PHL}	5.0		050	000	
t_{PLH} , $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 305 \text{ ns}$		5.0	_	350	600	
t_{PLH} , t_{PHL} = (0.36 ns/pF) C_L + 107 ns t_{PLH} , t_{PHL} = (0.26 ns/pF) C_L + 82 ns		10 15	_	125 95	250 190	
		10			100	
Clock to Serial out Q'S		5.0		230	460	
t_{PLH} , $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 350 \text{ ns}$		5.0	_			
t_{PLH} , $t_{PHL} = (0.36 \text{ ns/pF}) C_L + 149 \text{ ns}$		10 15	_	110 75	220 150	
t_{PLH} , $t_{PHL} = (0.26 \text{ ns/pF}) C_L + 62 \text{ ns}$		15	_	75	150	
Clock to Parallel out t_{PLH} , $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 375 \text{ ns}$		5.0	_	420	840	
t_{PLH} , $t_{PHL} = (0.35 \text{ ns/pF}) C_L + 177 \text{ ns}$		10	_	195	390	
t_{PLH} , $t_{PHL} = (0.35 \text{ ns/pF}) C_L + 122 \text{ ns}$		15	_	135	270	
				100	2,0	
Strobe to Parallel out		5.0	_	290	580	
t_{PLH} , $t_{PHL} = (0.90 \text{ ns/pF}) C_L + 245 \text{ ns}$		10	_	145	290	
t_{PLH} , $t_{PHL} = (0.36 \text{ ns/pF}) C L + 127 \text{ ns}$		15	_	100	200	
t_{PLH} , t_{PHL} = (0.26 ns/pF) C_L + 87 ns		13		100	200	
Output Enable to Output	tour	5.0		140	280	
t_{PHZ} , $t_{PZL} = (0.90 \text{ ns/pF}) C_L + 95 \text{ ns}$	t _{PHZ} , t _{PZL}	10		75	150	
t_{PHZ} , $t_{PZL} = (0.36 \text{ ns/PF}) C_L + 57 \text{ ns}$	ΨZL	15	_	55	110	
t_{PHZ} , $t_{PZL} = (0.26 \text{ ns/pF}) C_L + 42 \text{ ns}$						-
t_{PLZ} , $t_{PZH} = (0.90 \text{ ns/pF}) C_L + 180 \text{ ns}$	t _{PLZ} ,	5.0	_	225	450	
t_{PLZ} , $t_{PZH} = (0.36 \text{ ns/pF}) C_L + 77 \text{ ns}$	t _{PZH}	10	_	95	190	
t_{PLZ} , t_{PZH} = (0.26 ns/pF) C_L + 57 ns		15	_	70	140	
Setup Time	t _{su}	5.0	125	60	-	ns
Data in to Clock		10	55	30	_	
		15	35	20	_	
Hold Time Clock to Data	t _h	5.0	0	- 40 10	_	ns
Clock to Data		10 15	20 20	- 10 0	_	
Clock Pulse Width, High	twH	5.0	200	100	_	ns
, č	****	10	100	50	_	
		15	83	40	_	
Clock Rise and Fall Time	t _{r(cl)}	5	-	-	15	μs
	t _{f(cl)}	10	_	_	5.0	
		15	-	-	4.0	
Clock Pulse Frequency	f _{cl}	5.0	_	2.5	1.25	MHz
		10	_	5.0	2.5	
2		15	-	6.0	3.0	
Strobe Pulse Width	t_WL	5.0	200	100	_	ns
		10	80	40	_	
		15	70	35	-	

^{5.} The formulas given are for the typical characteristics only at 25°C.
6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3-STATE TEST CIRCUIT

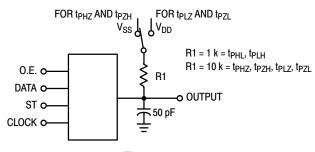
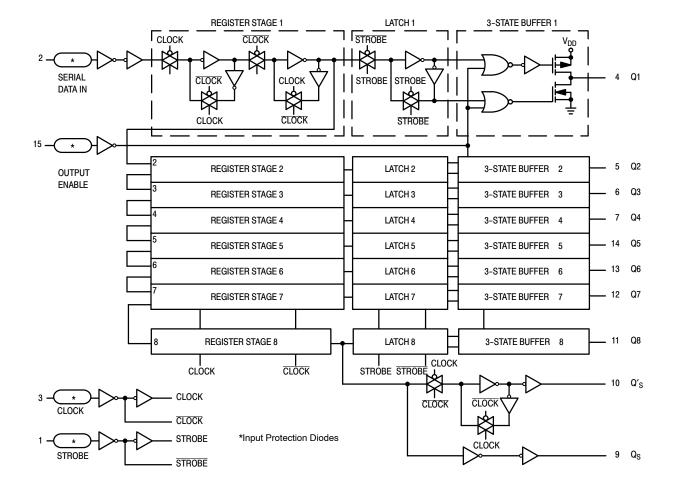
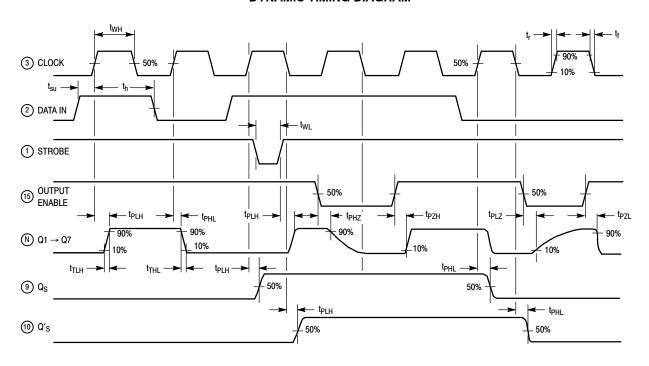


Figure 1.

BLOCK DIAGRAM

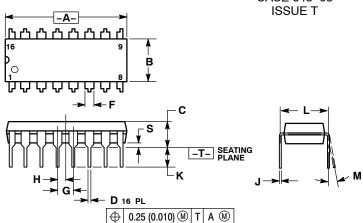


DYNAMIC TIMING DIAGRAM



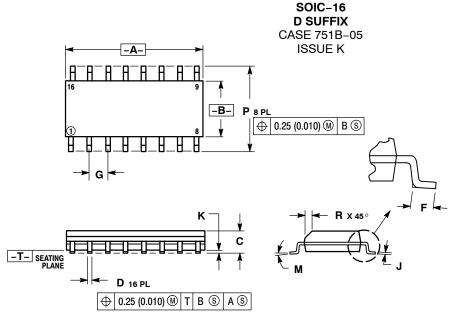
PACKAGE DIMENSIONS

PDIP-16 **P SUFFIX** CASE 648-08



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- DIMENSIONING AND TOLEHANCING P ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. DIMENSION B DOES NOT INCLUDE
- MOLD FLASH.
- 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27	BSC	
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
Ĺ	0.295	0.305	7.50	7.74	
М	0°	10 °	0°	10 °	
S	0.020	0.040	0.51	1 01	



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

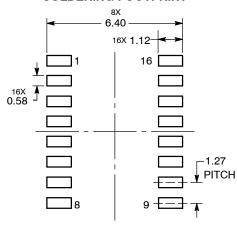
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

- PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL
 IN EXCESS OF THE D DIMENSION AT
 MAXIMUM MATERIAL CONDITION.

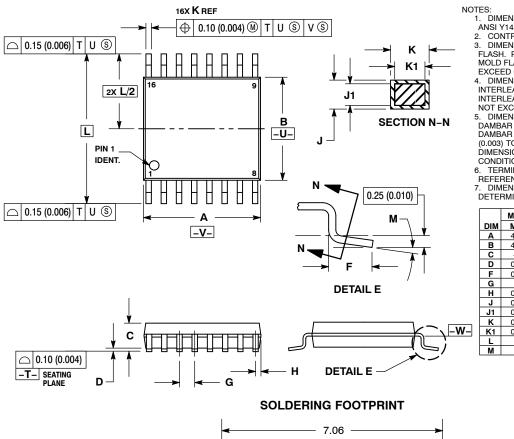
	MILLIN	IETERS	S INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
Ĺ	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

SOLDERING FOOTPRINT



PACKAGE DIMENSIONS

TSSOP-16 **DT SUFFIX** CASE 948F-01 **ISSUE B**



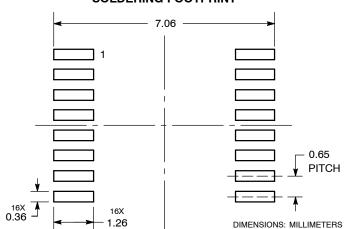
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 2.15 (2.008) PER SIDE EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE

 - 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

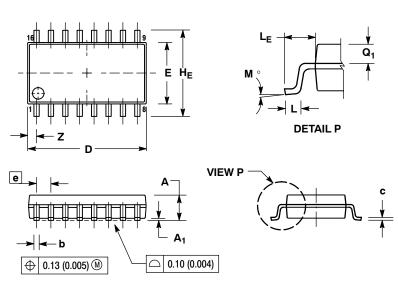
 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
 - 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

_				
	MILLIN	IETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
Н	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252	BSC
М	0°	8°	0 °	8 °



PACKAGE DIMENSIONS

SOEIAJ-16 **F SUFFIX** CASE 966-01 **ISSUE A**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER. I. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15
- (0.006) PER SIDE. REFERENCE ONLY.
 5. THE LEAD WIDTH DIMENSION (b) DOES NOT
- INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION.

 DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	i	2.05	-	0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
C	0.10	0.20	0.007	0.011
D	9.90	10.50	0.390	0.413
Е	5.10	5.45	0.201	0.215
е	1.27	BSC	0.050	BSC
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10°	0°	10 °
Q ₁	0.70	0.90	0.028	0.035
Z	-	0.78	-	0.031

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